	ESC	C	DC	DCUMENT	CHANGE REQUEST				
DCR number	863	Changes re	quired for: Gen	eral	Originator: Jean-Marc Bureau				
Date: 2014/11/17 Date sent: 2014/05/28			2014/05/28		Organisation: Cobham				
Status: IMPLE	EMENTED								
Title:	itle: Diodes Microwave Silicon Multiplier Varactor, based on types DH252,256, 267,292, 294								
Number:	5512/016		Issue:	4					
Other documen	Other documents affected:								
Page:									
28									
Paragraph:									
Appendix A									
Original wording:									
AGREED DEVIATIONS FOR TEMEX (F)									
Proposed wording:									
AGREED DEVIATIONS FOR COBHAM MICROWAVE (F)									
Justification:									
company name has changed since 2004									

	ESC	C	D	OCUMENT	CHANGE REQUEST				
DCR number	863	Changes re	quired for: Ger	Originator: Jean-Marc Bureau					
Date: 2014/11/17 Date sent: 2014/05/28			2014/05/28		Organisation: Cobham				
Status: IMPLE	EMENTED								
Title:	Diodes Microwave Silicon Multiplier Varactor, based on types DH252,256, 267,292, 294								
Number:	5512/016		Issue:	4					
Other documen	Other documents affected:								
Page:									
24									
Paragraph:									
Table 4, Note 3									
Original wording:									
3. Rounded upwards to nearest 0.01pF value.									
Proposed wording:									
3. Rounded upwards to nearest 0.01pF value. If CT 0,50 pF then $= \pm 10\%$									
Justification:									
 to better reflect actual parameters, especially of the smallest diodes (i.e. DH267) to harmonize with similar PIN diode specifications, especially with 5513/032 to 5513/038 from the same certificate 225E 									

	ESC	<u> </u>	DC	DCUMENT	CHANGE REQUEST			
DCR number	863	Changes re-	quired for: Gen	eral	Originator: Jean-Marc Bureau			
Date: 2014/11	/17	Date sent: 2	2014/05/28		Organisation: Cobham			
Status: IMPLEMENTED								
Title:	Diodes Microwave Silicon Multiplier Varactor, based on types DH252,256, 267,292, 294							
Number:	5512/016 Issue:			4				
Other documen	Other documents affected:							
Page:								
22								
Paragraph:								
Table 2, Note 3								
Original wording:								
Vf max = 0.9 V								
Proposed wordi	ng:							
Vf max = 1.1 V								
Justification:								
 to better reflect actual parameters, especially of the smallest diodes (i.e. DH267) to harmonize with similar PIN diode specifications, especially with 5513/032 to 5513/038 from the same certificate 225E 								
Attachments:								
N/A								
Modifications:								
On page 1 of the PDF version for proposed wording, it should read "Rounded upwards to nearest 0.01pF value. If CT less than or equal to 0,50 pF then delta = ± 10% " Justification: The symbols (lower or equal to) and (delta) have disappeared in the PDF conversion.								
Approval signature:								
R. C. Hari-r								
Date signed:								
2014-11-17								